

Device Modeling Report

COMPONENTS: Power MOSFET (Model Parameter)
PART NUMBER: SSM3K15FU
MANUFACTURER: TOSHIBA
Body Diode (Model Parameter) / ESD Protection Diode

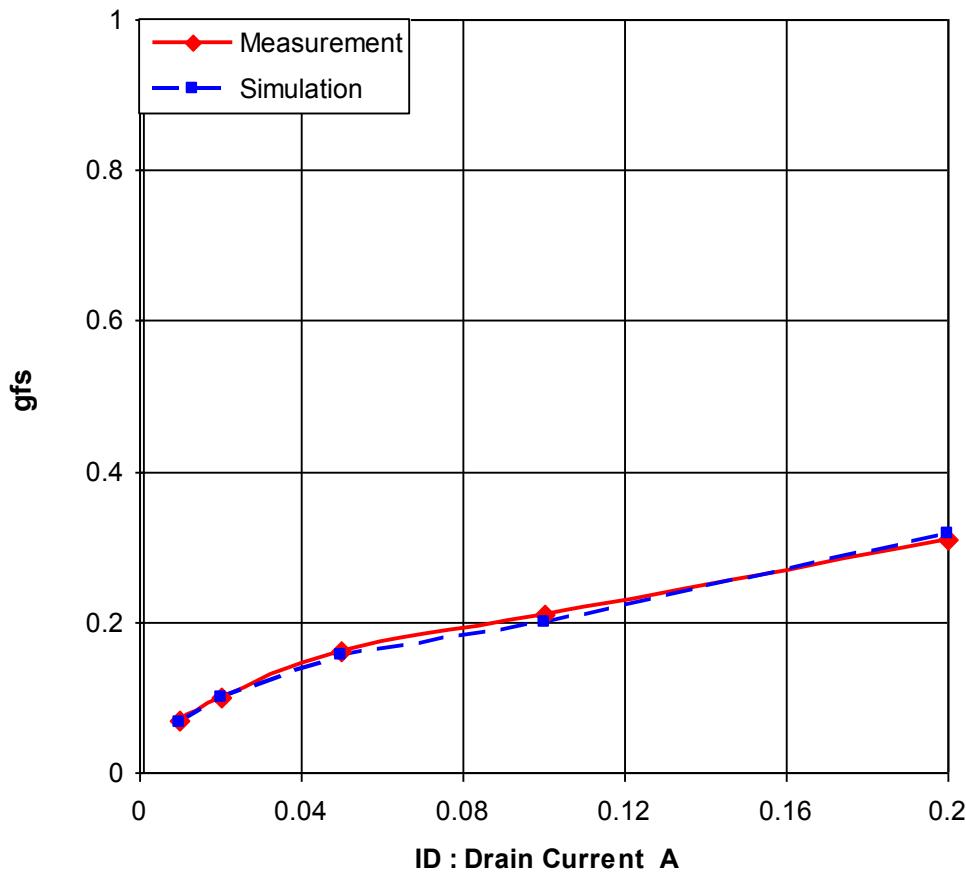


MOSFET MODEL

Pspice model parameter	Model description
LEVEL	
L	Channel Length
W	Channel Width
KP	Transconductance
RS	Source Ohmic Resistance
RD	Ohmic Drain Resistance
VTO	Zero-bias Threshold Voltage
RDS	Drain-Source Shunt Resistance
TOX	Gate Oxide Thickness
CGSO	Zero-bias Gate-Source Capacitance
CGDO	Zero-bias Gate-Drain Capacitance
CBD	Zero-bias Bulk-Drain Junction Capacitance
MJ	Bulk Junction Grading Coefficient
PB	Bulk Junction Potential
FC	Bulk Junction Forward-bias Capacitance Coefficient
RG	Gate Ohmic Resistance
IS	Bulk Junction Saturation Current
N	Bulk Junction Emission Coefficient
RB	Bulk Series Resistance
PHI	Surface Inversion Potential
GAMMA	Body-effect Parameter
DELTA	Width effect on Threshold Voltage
ETA	Static Feedback on Threshold Voltage
THETA	Modility Modulation
KAPPA	Saturation Field Factor
VMAX	Maximum Drift Velocity of Carriers
XJ	Metallurgical Junction Depth
UO	Surface Mobility

Transconductance Characteristic

Circuit Simulation Result

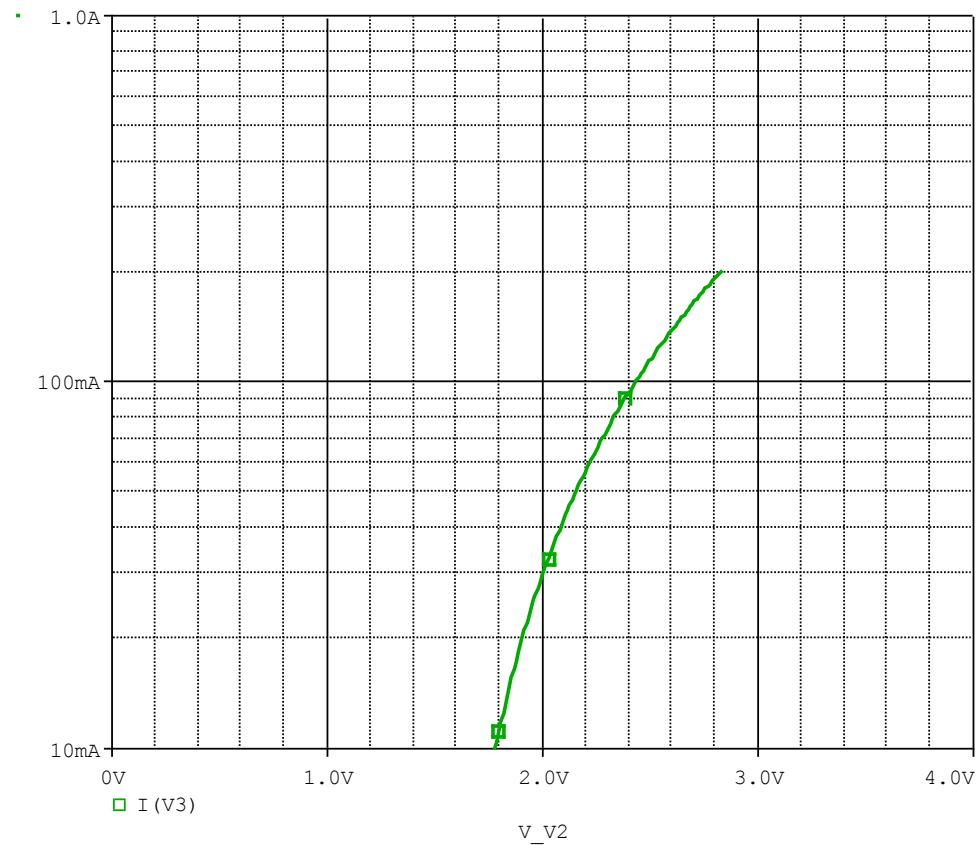


Comparison table

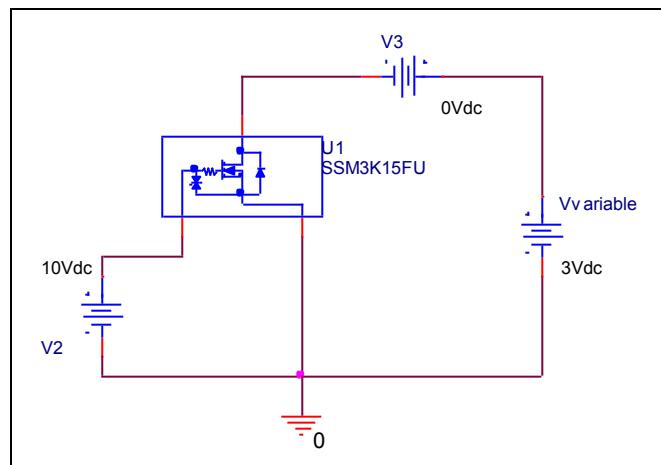
Id(A)	gfs		Error(%)
	Measurement	Simulation	
0.010	0.069	0.067	-2.899
0.020	0.100	0.100	0.000
0.050	0.162	0.156	-3.704
0.100	0.210	0.200	-4.762
0.200	0.310	0.317	2.258

V_{gs}-I_d Characteristic

Circuit Simulation result

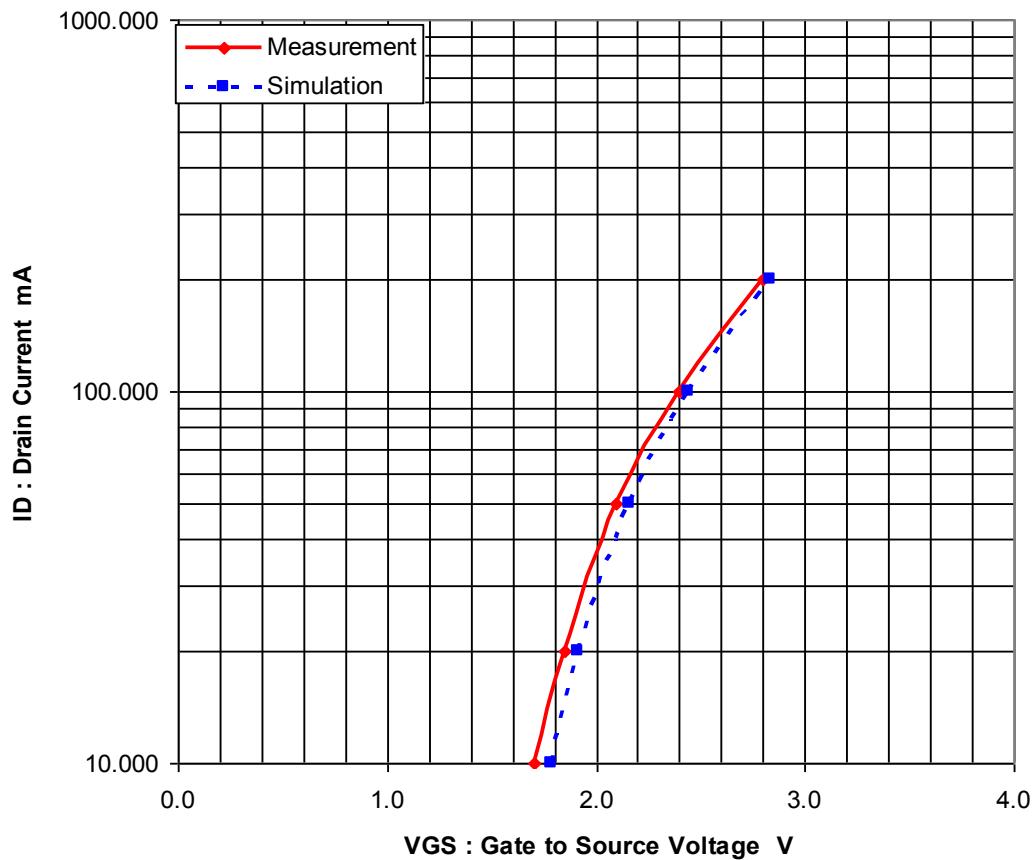


Evaluation circuit



Comparison Graph

Circuit Simulation Result

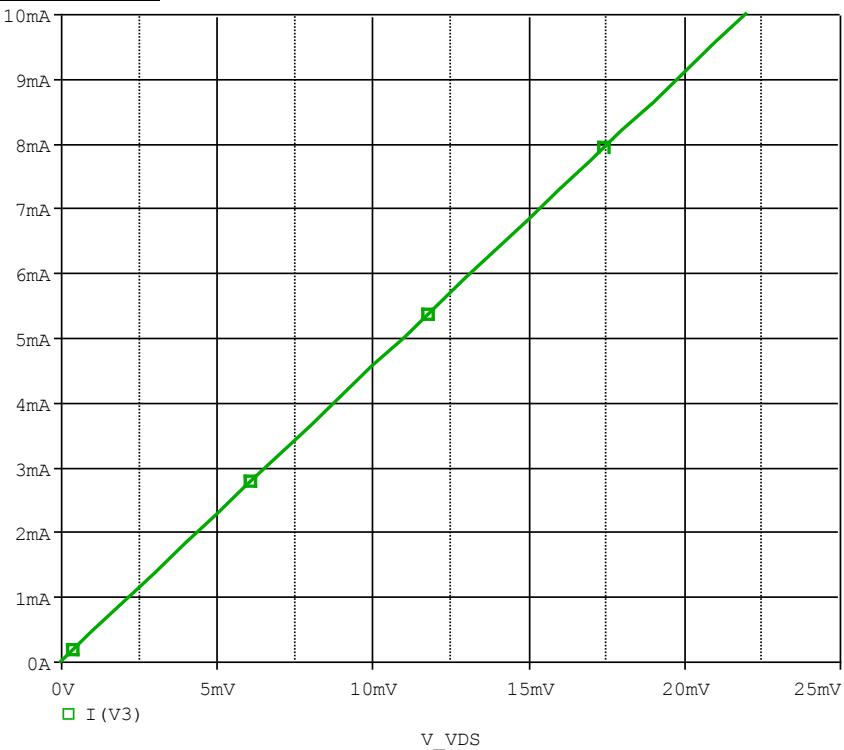


Simulation Result

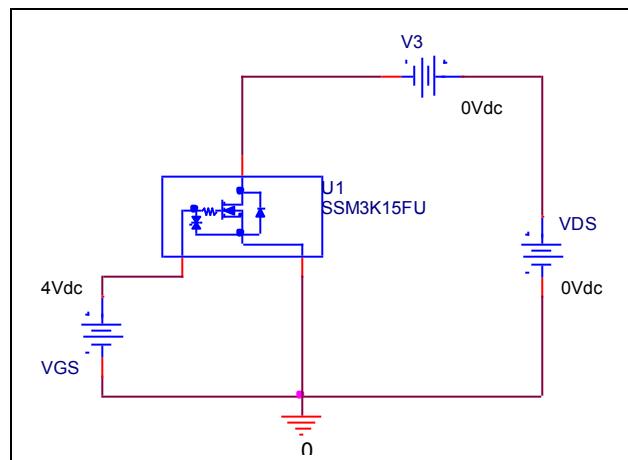
I_D (mA)	V_{GS} (V)		Error (%)
	Measurement	Simulation	
10.000	1.700	1.785	5.000
20.000	1.850	1.911	3.297
50.000	2.100	2.159	2.810
100.000	2.400	2.439	1.625
200.000	2.800	2.831	1.107

Rds(on) Characteristic

Circuit Simulation result



Evaluation circuit

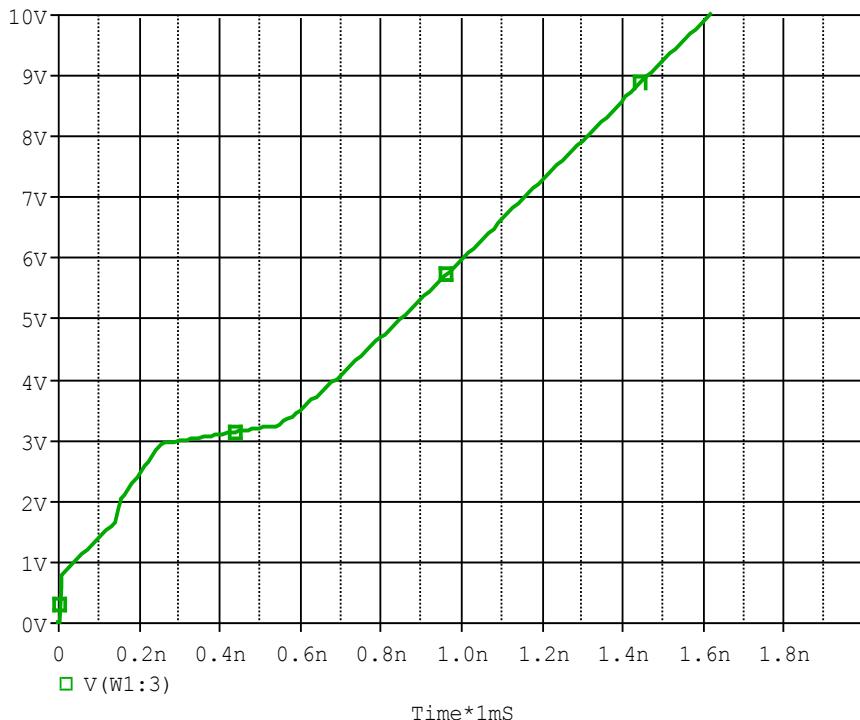


Simulation Result

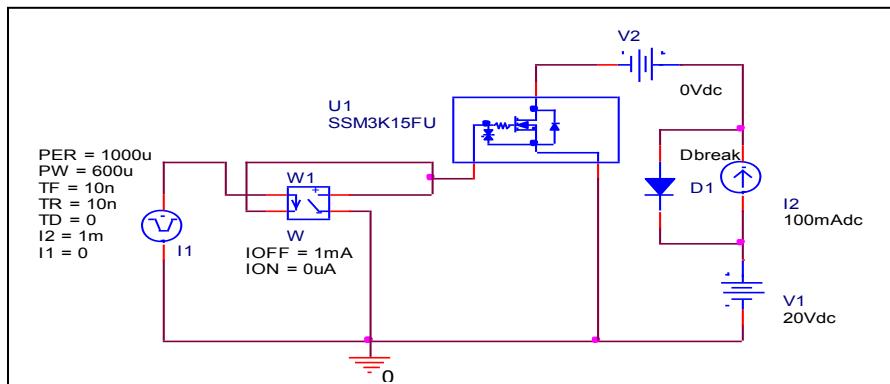
I _D =10mA, V _{GS} =4V	Measurement	Simulation	Error (%)
R _{DS} (on) (Ω)	2.200	2.198	-0.091

Gate Charge Characteristic

Circuit Simulation result



Evaluation circuit

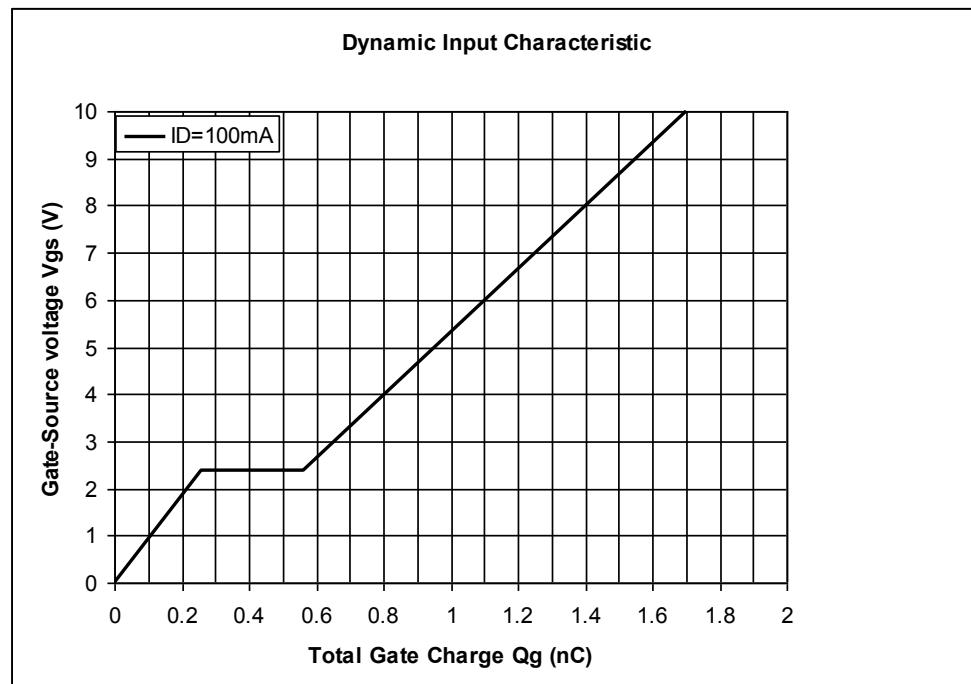


Simulation Result

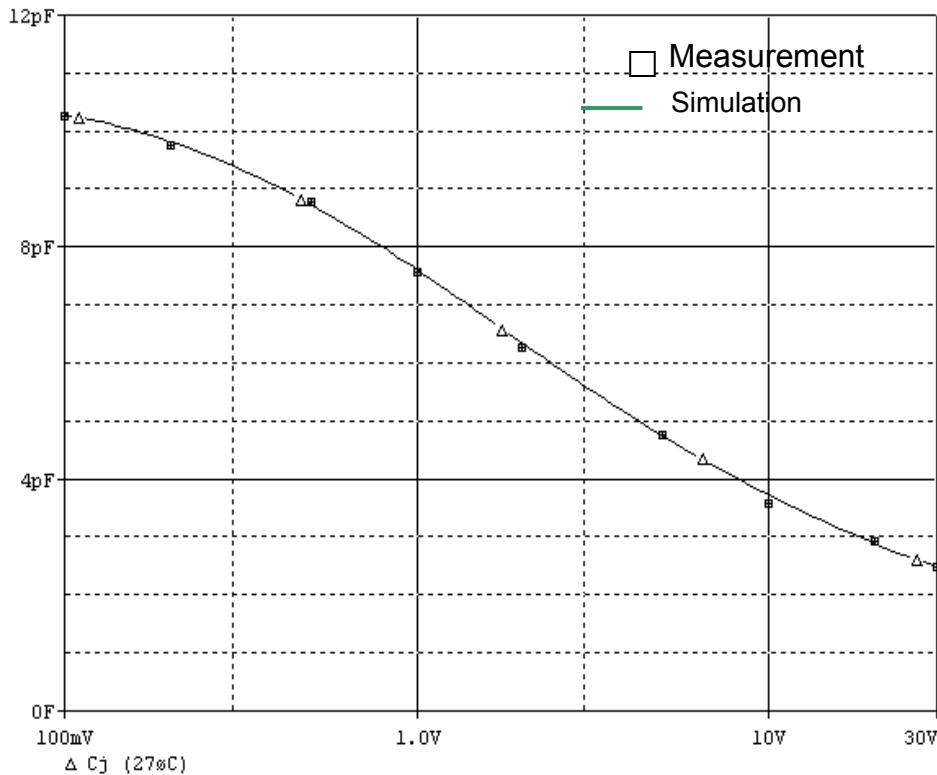
$V_{DD}=20V, I_D=100mA, V_{GS}=10V$	Measurement	Simulation	Error (%)
Qgs(nc)	0.260	0.259	-0.385
Qgd(nc)	0.300	0.301	0.333
Qg(nc)	1.700	1.619	-4.765

Gate Charge Characteristic

Reference



Capacitance Characteristic



Simulation Result

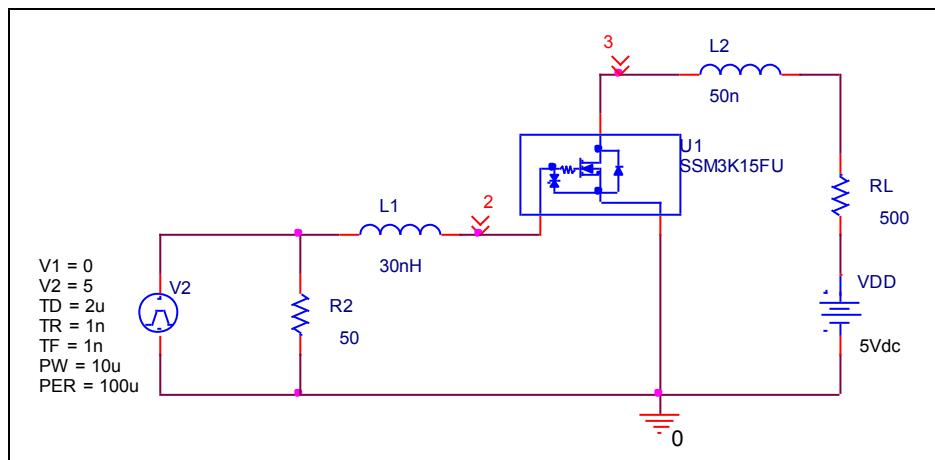
V_{DS} (V)	Cbd(pF)		Error(%)
	Measurement	Simulation	
0.100	10.300	10.299	-0.010
0.200	9.780	9.815	0.358
0.500	8.800	8.750	-0.568
1.000	7.600	7.610	0.132
2.000	6.300	6.340	0.635
5.000	4.800	4.740	-1.250
10.000	3.600	3.700	2.778
20.000	2.950	2.870	-2.712
30.000	2.500	2.480	-0.800

Switching Time Characteristic

Circuit Simulation result



Evaluation circuit

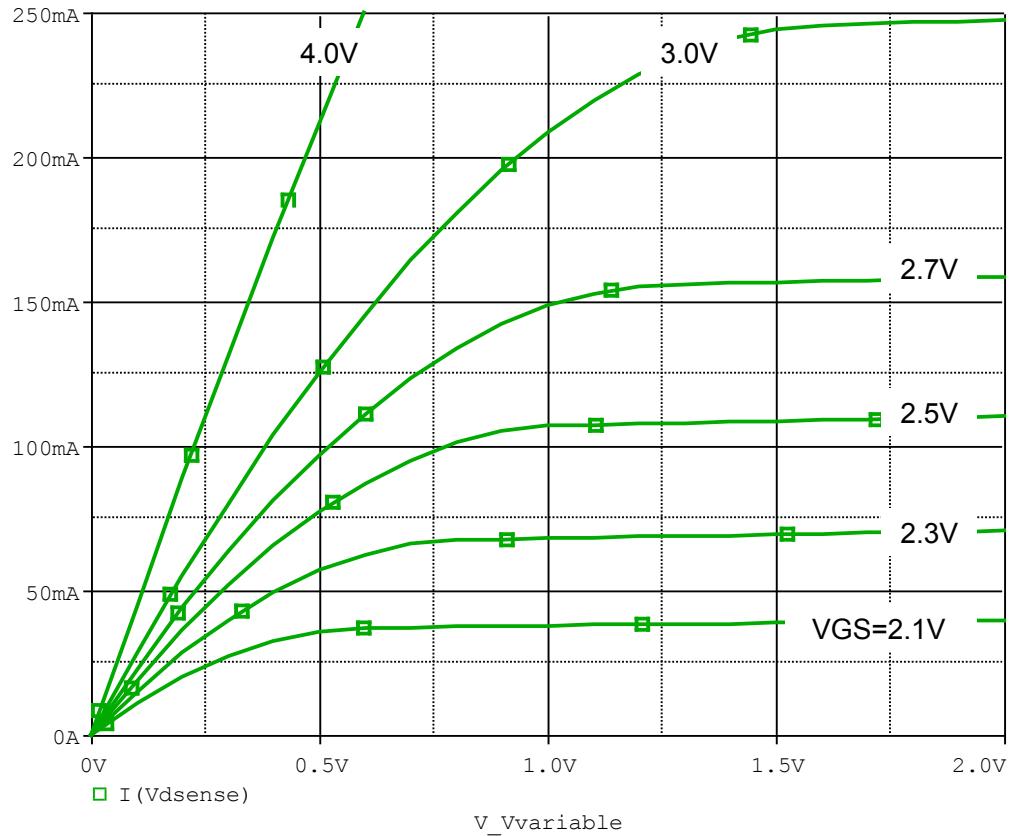


Simulation Result

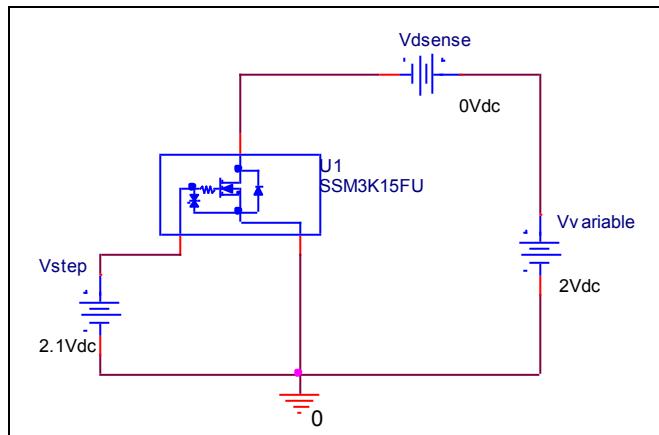
$I_D=10mA$, $V_{DD}=5V$ $V_{GS}=5V$	Measurement	Simulation	Error(%)
Ton(ns)	50.000	50.033	0.066

Output Characteristic

Circuit Simulation result



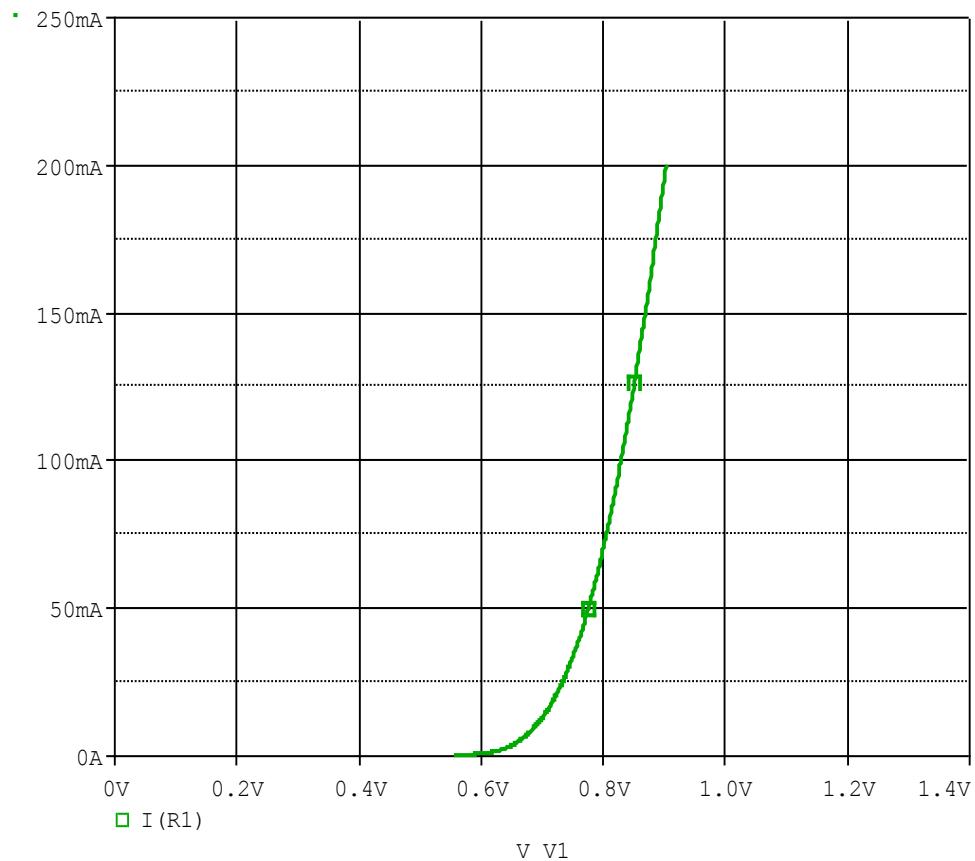
Evaluation circuit



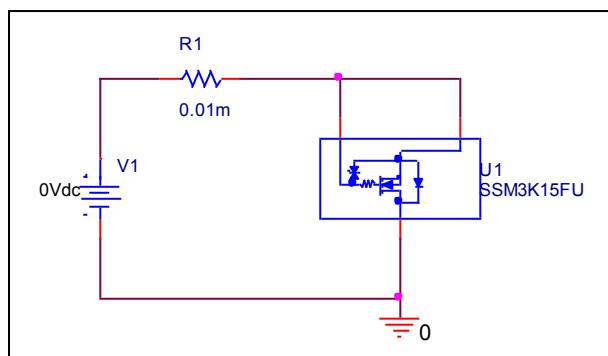
BODY DIODE SPICE MODEL

Forward Current Characteristic

Circuit Simulation Result

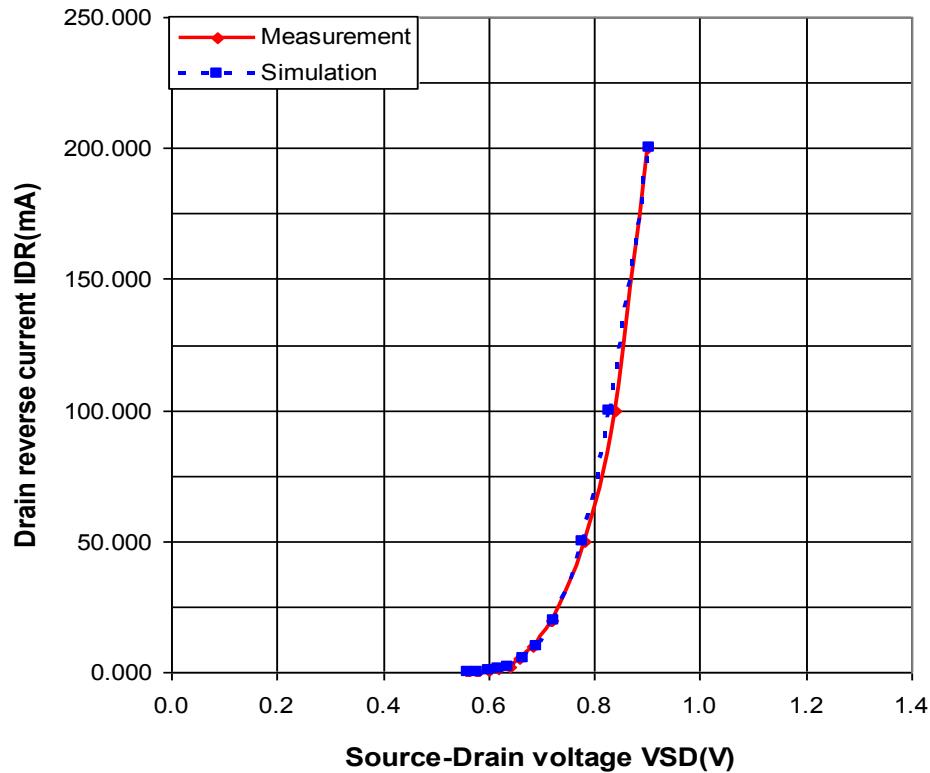


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

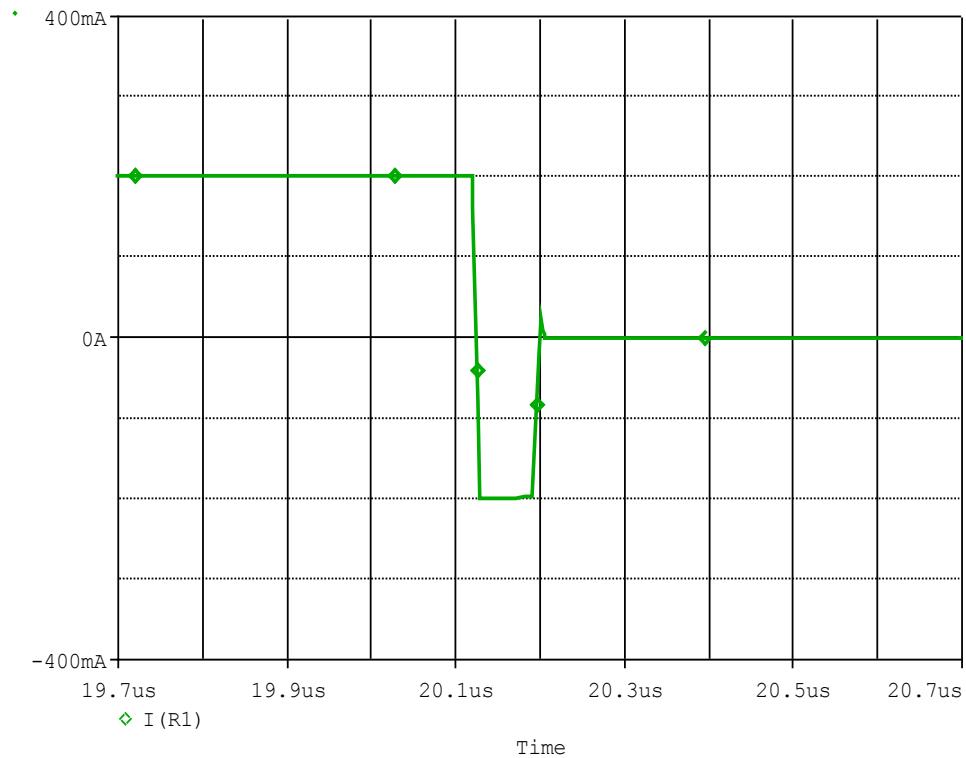


Simulation Result

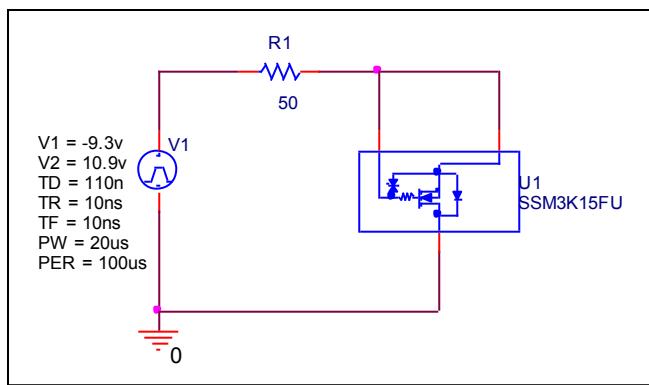
IDR(A)	VSD(V) Measurement	VSD(V) Simulation	%Error
0.100	0.560	0.561	0.179
0.200	0.580	0.578	-0.345
0.500	0.600	0.601	0.167
1.000	0.620	0.619	-0.161
2.000	0.640	0.637	-0.469
5.000	0.660	0.664	0.606
10.000	0.685	0.691	0.876
20.000	0.720	0.724	0.556
50.000	0.780	0.778	-0.256
100.000	0.840	0.830	-1.190
200.000	0.900	0.904	0.444

Reverse Recovery Characteristic

Circuit Simulation Result



Evaluation Circuit

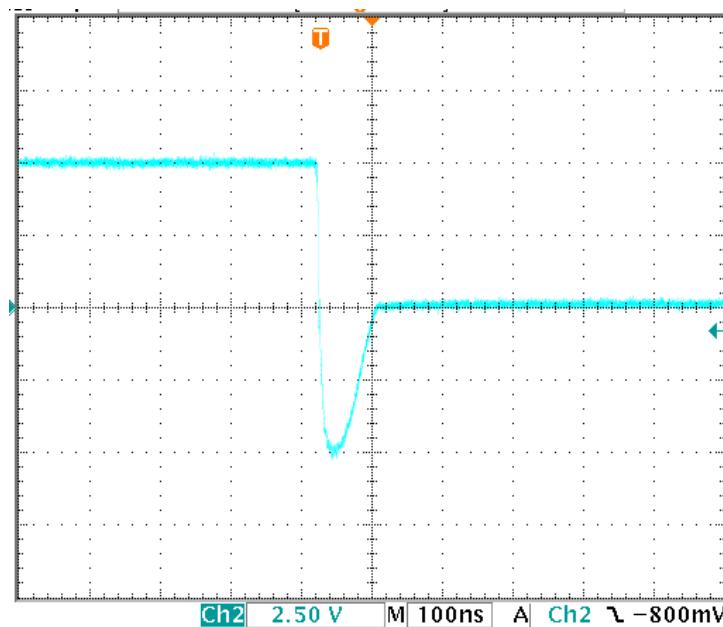


Compare Measurement vs. Simulation

	Measurement	Simulation	Error (%)
$T_{rr}(ns)$	73.600	73.609	0.012

Reverse Recovery Characteristic

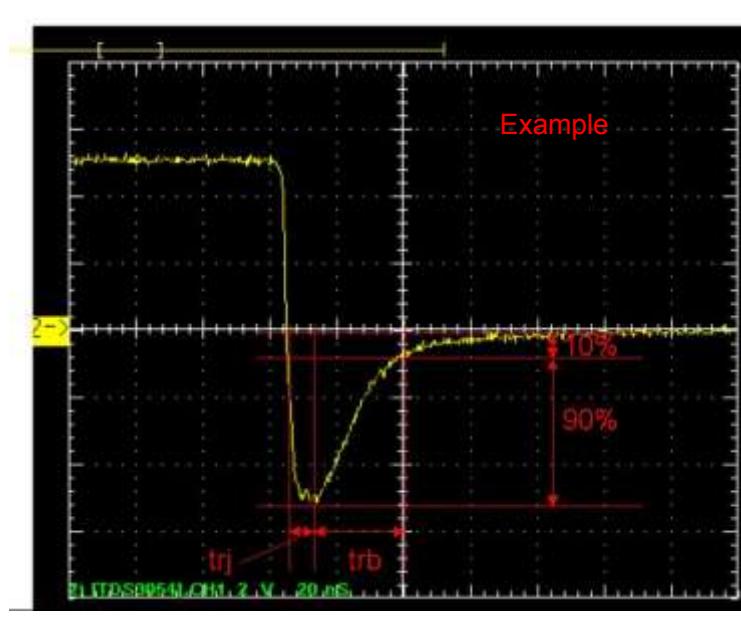
Reference



Trj=32(ns)

Trb=41.6(ns)

Conditions: Ifwd=Irev=0.2(A), RI=50

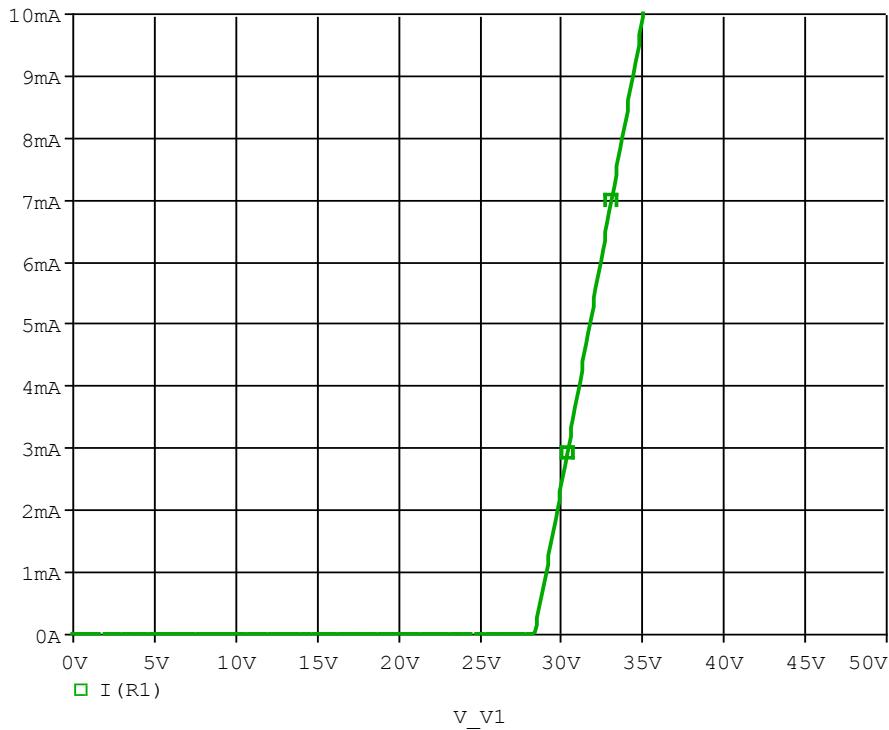


Relation between trj and trb

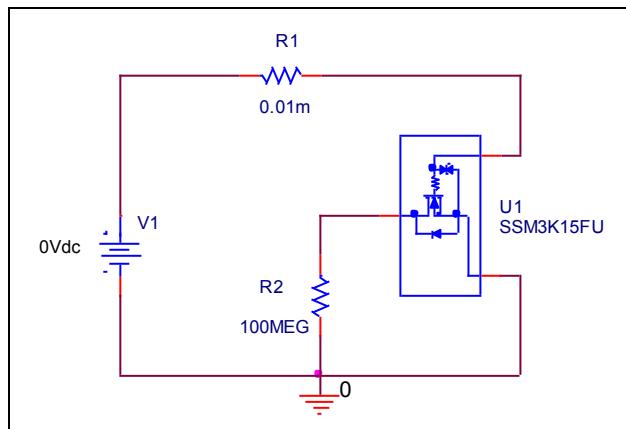
ESD PROTECTION DIODE SPICE MODEL

Zener Voltage Characteristic

Circuit Simulation Result



Evaluation Circuit



Zener Voltage Characteristic

Reference

